



# PDP93328TA11

## SMD Type Photo Diode

### Features

- Small double-end package
- High reliability
- High Reverse Breakdown
- High Sensitivity
- Fast Response time
- RoHS compliance

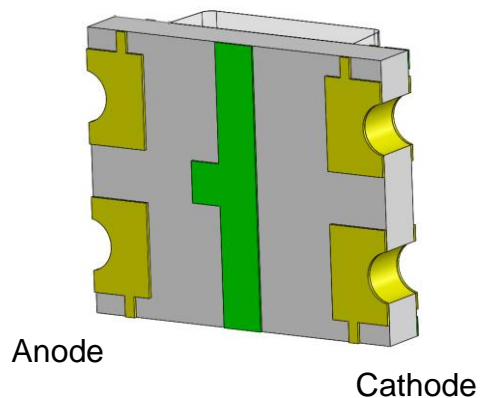
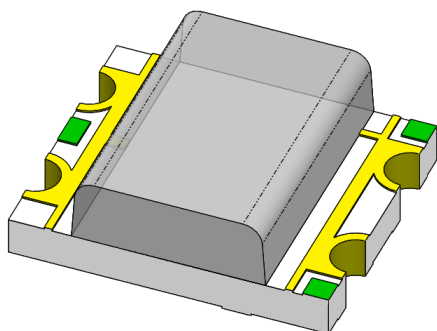
### Applications

- Infrared sensor

### Description

The PDP93328TA11 is a silicon photo diode housed in a miniature SMD package. The device has wide spectral sensitivity range from 400 to 1100nm.

### Package Outline



### Schematic





# PDP93328TA11

## SMD Type Photo Diode

### Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
V <sub>R</sub>	Reverse Voltage	33	V	
T <sub>opr</sub>	Operating Temperature	-40 ~ +85	°C	
T <sub>stg</sub>	Storage Temperature	-40 ~ +100	°C	
T <sub>sol</sub>	Soldering Temperature	260	°C	1
P <sub>to</sub>	Total Power Dissipation	150	mW	

### Electro-Optical Characteristics *TA = 25°C (unless otherwise specified)*

#### Optical Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
λ	Spectral Bandwidth	-	400	-	1100	nm	
λ <sub>P</sub>	Peak Sensitivity	-	-	940	-	nm	
θ <sub>1/2</sub>	View Angle	V <sub>R</sub> =5V	-	±55	-	deg	

#### Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
I <sub>D</sub>	Dark Current	Ee=0mW /cm <sup>2</sup> V <sub>R</sub> =10V	-	-	10	nA	
V <sub>BR</sub>	Reverse Breakdown Voltage	Ee=0mW /cm <sup>2</sup> I <sub>R</sub> =100μA	33	-	-	V	
V <sub>OC</sub>	Open-Circuit Voltage	Ee=1mW /cm <sup>2</sup>	-	0.3	-	V	
I <sub>SC</sub>	Short-Circuit Current	λ <sub>P</sub> =940nm	-	9.0	-	μA	
I <sub>RL</sub>	Reverse Light Current	Ee=1mW /cm <sup>2</sup> λ <sub>P</sub> =940nm, V <sub>R</sub> =5V	5.0	9.7	-	μA	
C <sub>T</sub>	Transition Capacitance	Ee=0mW /cm <sup>2</sup> f=1MHz, V <sub>R</sub> =5V	-	4.76	-	pF	



# PDP93328TA11

## SMD Type Photo Diode

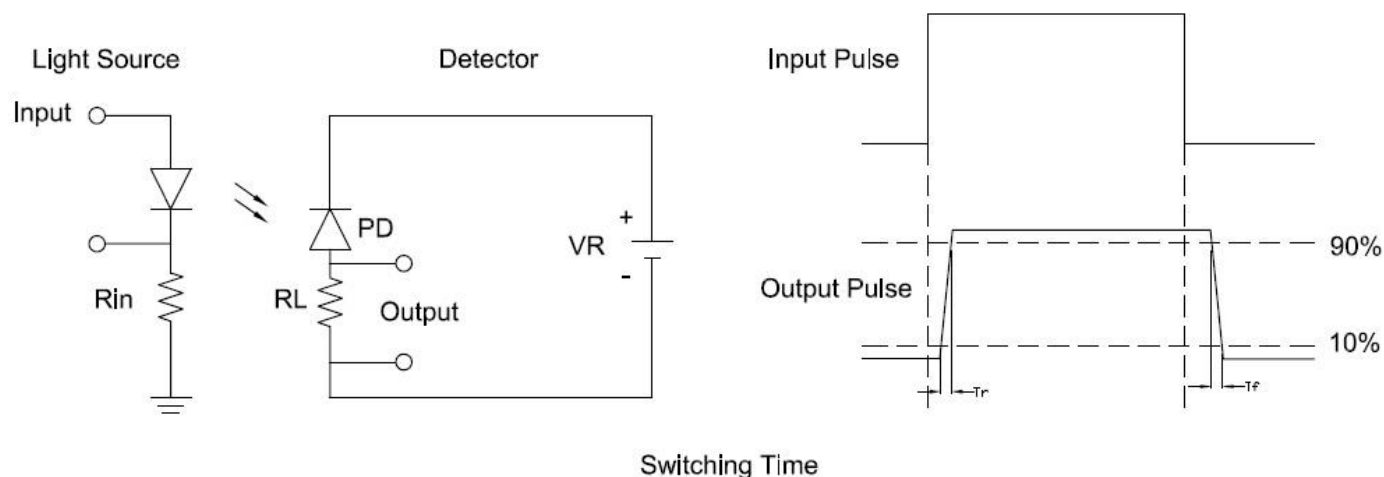
### Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$t_r$	Rise Time	$V_R = 10V, R_L = 10k\Omega$	-	770	-	ns	2
$t_f$	Fall Time		-	720	-		

**Notes:**

1 : Soldering time  $\leq 5$  seconds.

2 : Test circuit :





## Typical Characteristic Curves

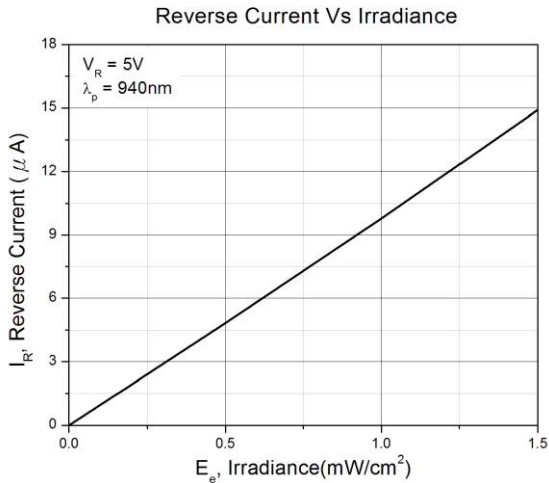


Figure 1

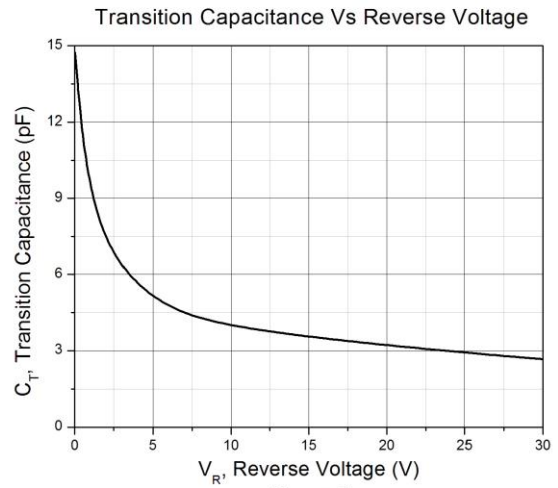


Figure 2

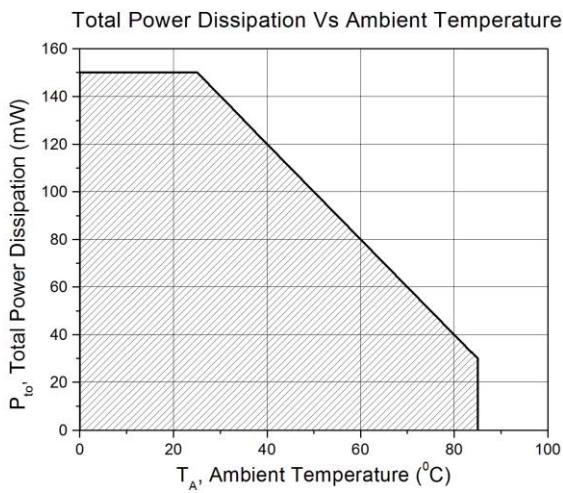


Figure 3

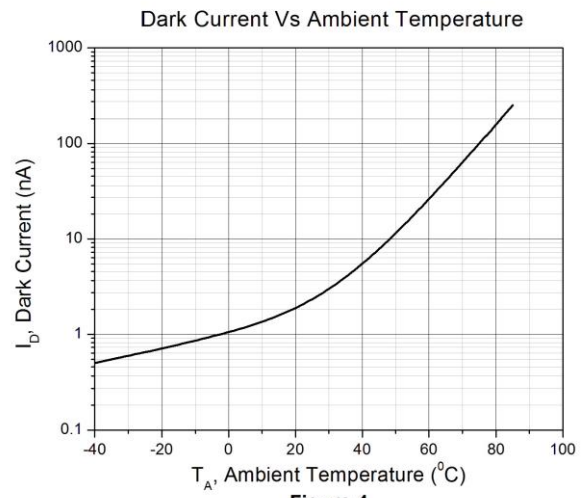


Figure 4

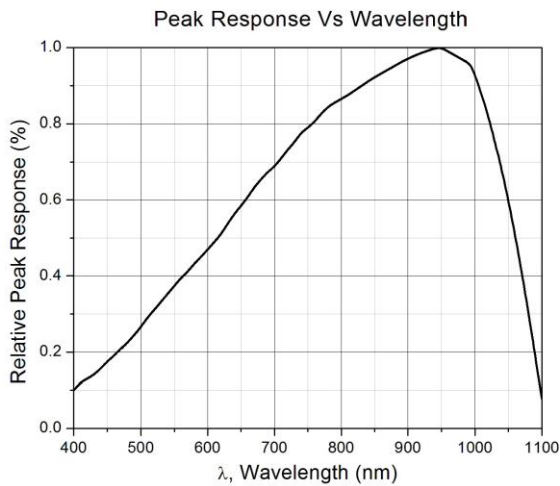


Figure 5

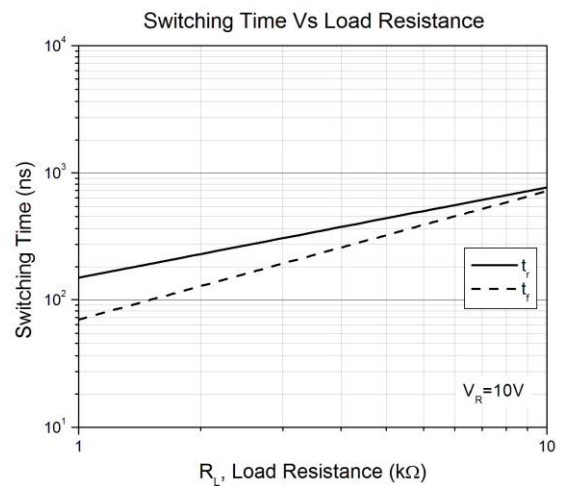
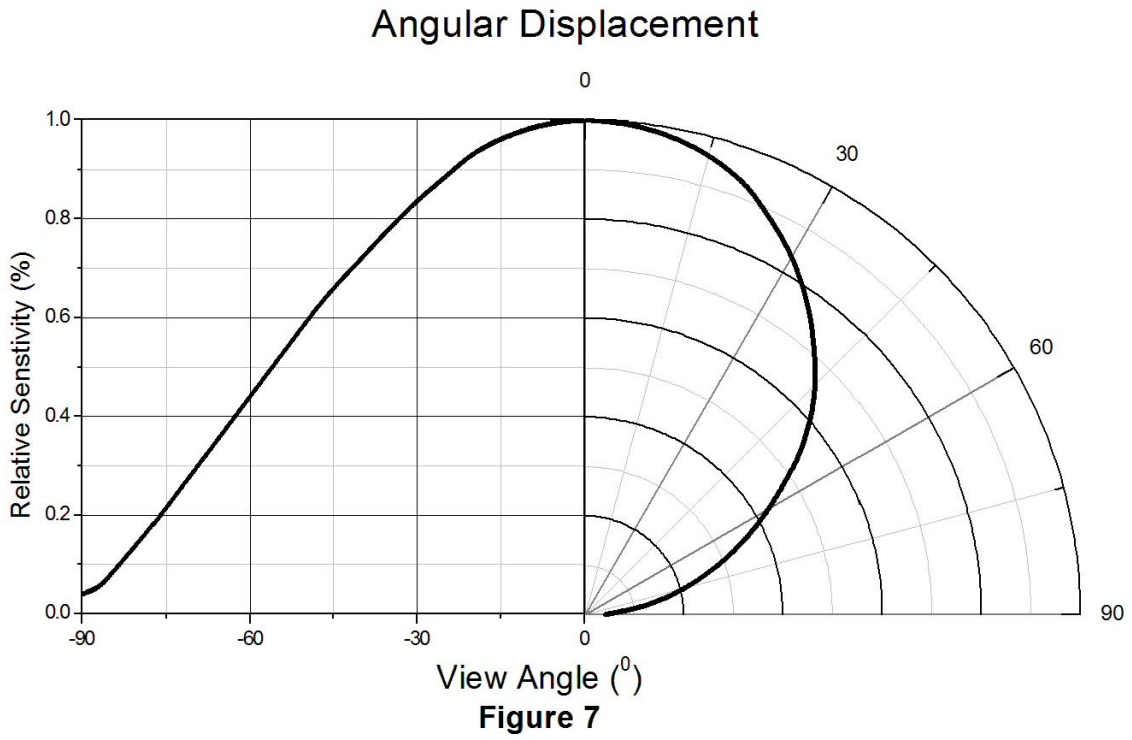


Figure 6



Typical Characteristic Curves

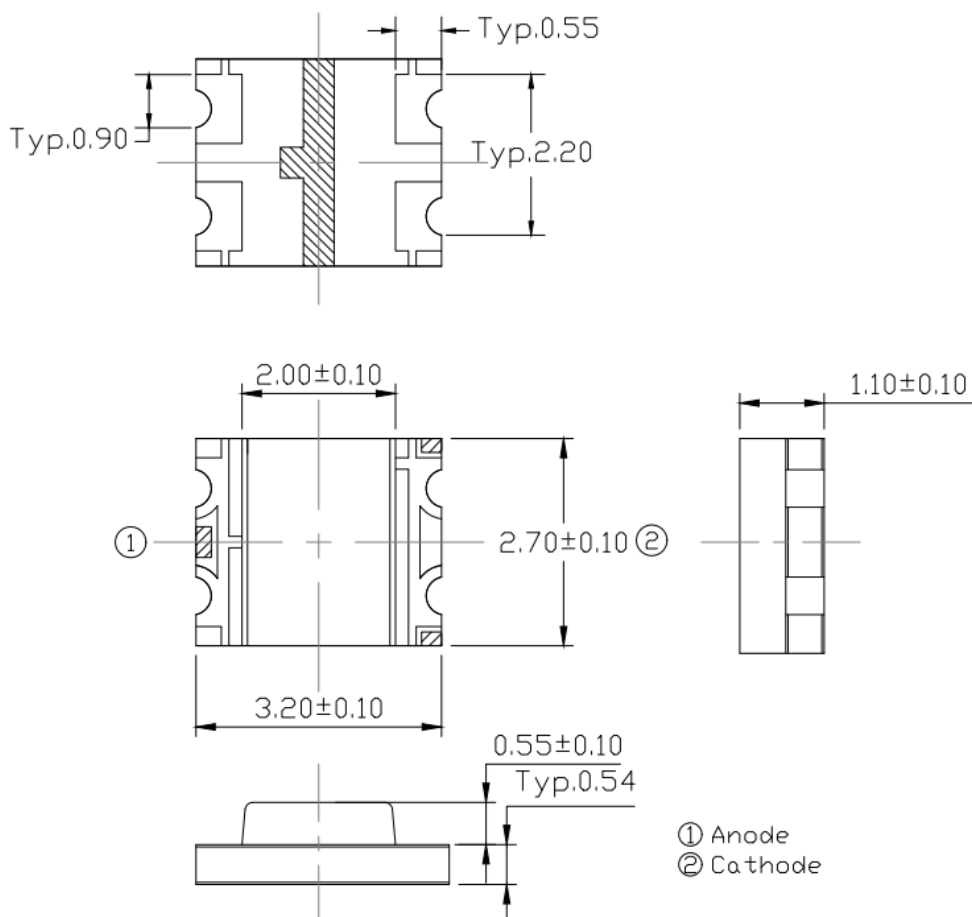




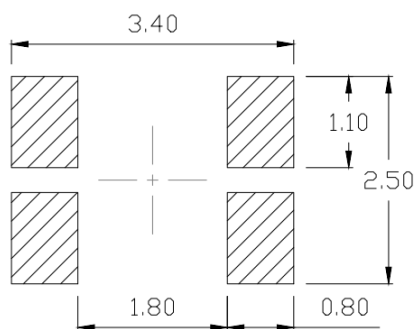
# PDP93328TA11

## SMD Type Photo Diode

### Package Dimension *All dimensions are in mm, unless otherwise stated*



### Recommended Soldering Mask *All dimensions are in mm, unless otherwise stated*



### Ordering Information

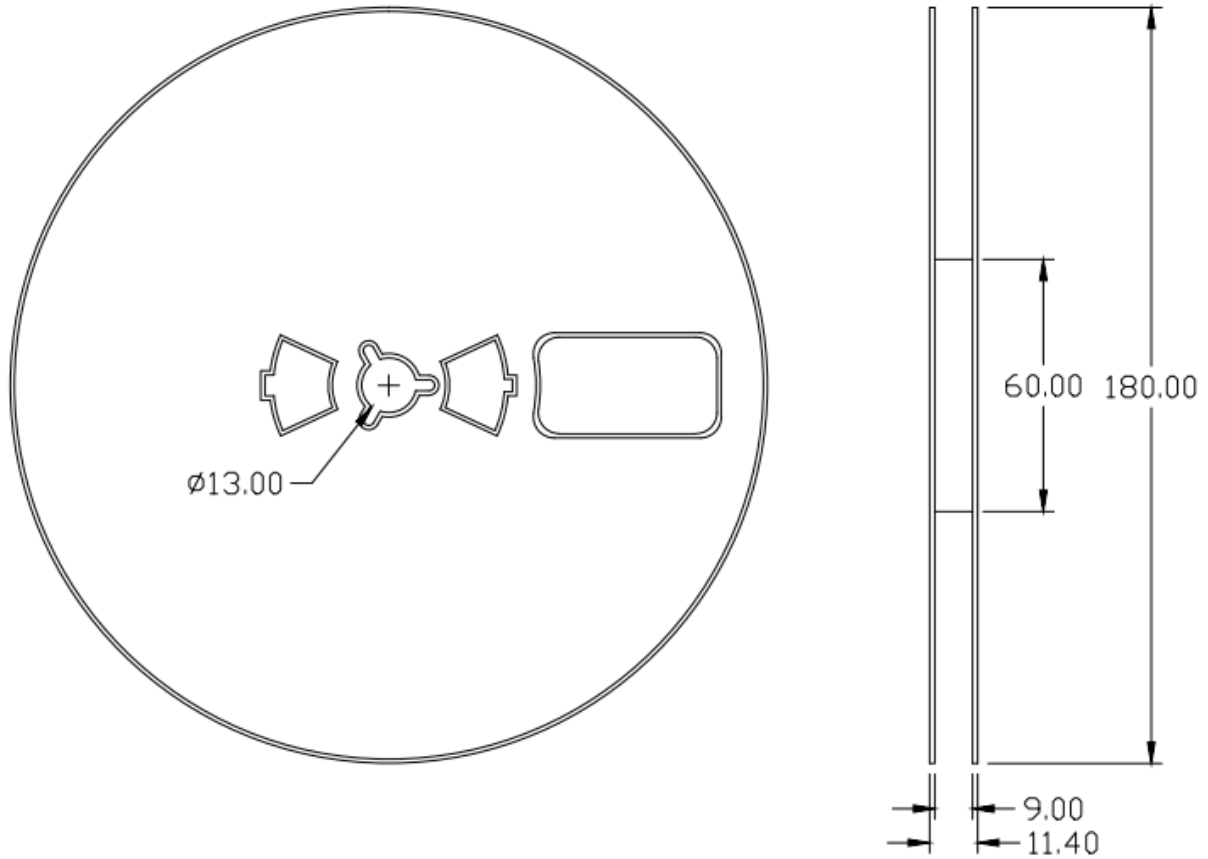
Part Number	Description	Quantity
PDP93328TA11	Tape & Reel	3000 pcs



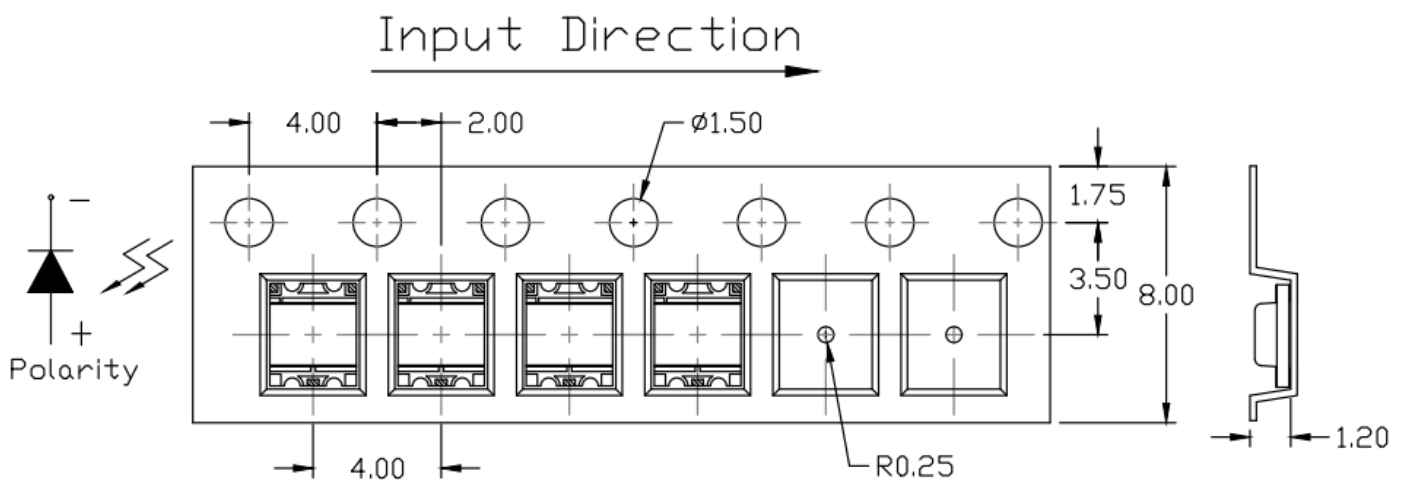
# PDP93328TA11

## SMD Type Photo Diode

### Reel Dimension *All dimensions are in mm, unless otherwise stated*

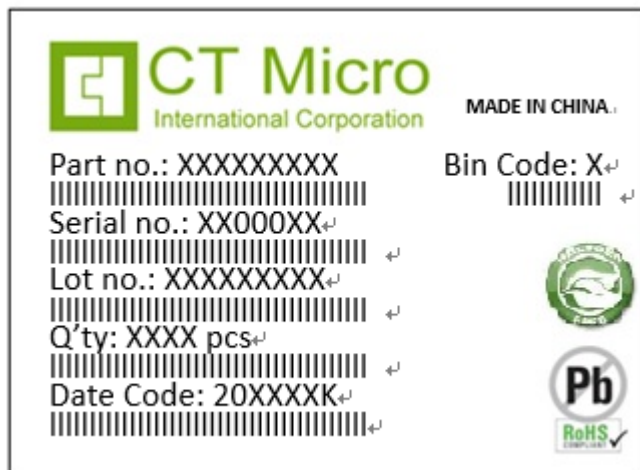


### Tape Dimension *All dimensions are in mm, unless otherwise stated*





### Label Form Specification



Part no: CTM Production Number  
Serial no: Production Number  
Lot no: Lot number  
Q'ty: Packing Quantity  
Date Code: Manufacture Date  
Bin Code: I<sub>RL</sub> Ranks  
MADE IN CHINA: Production Place

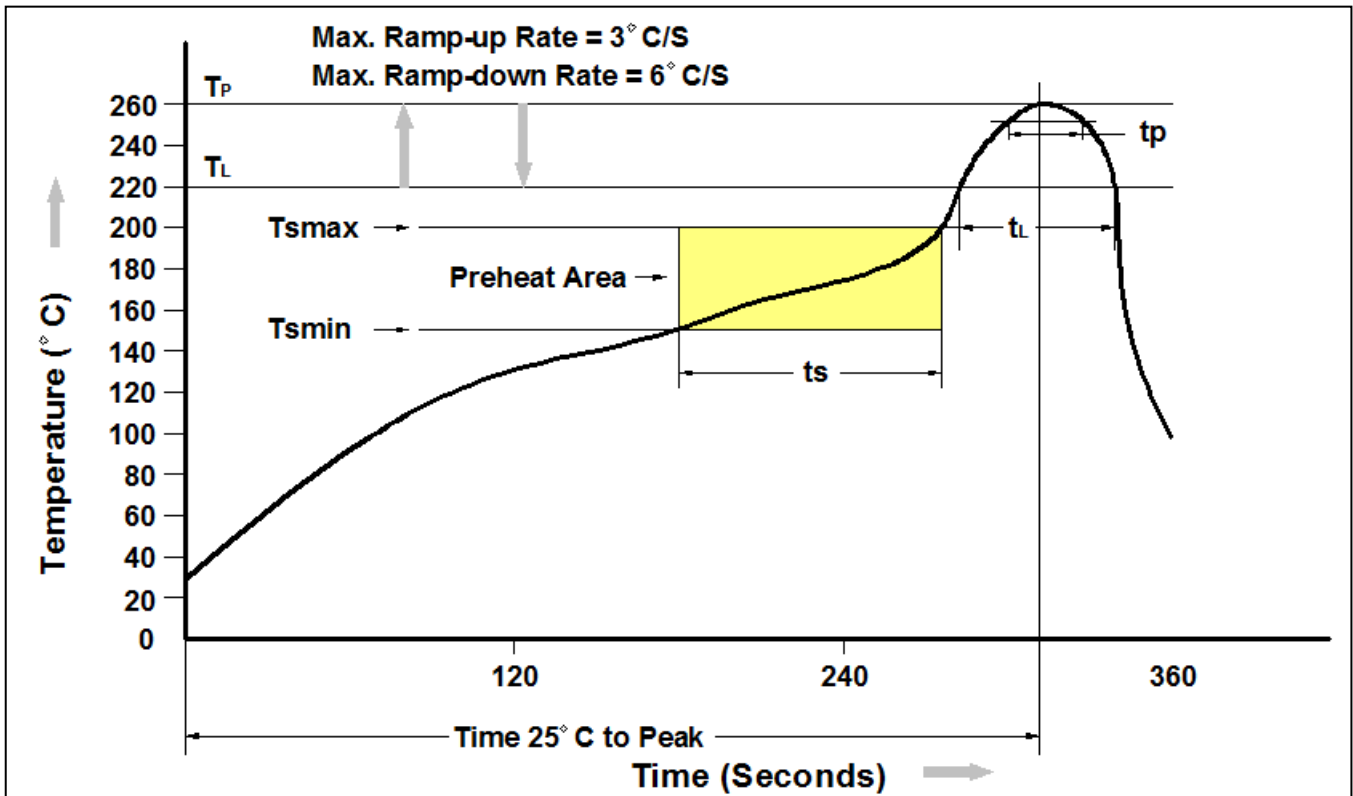
### Storage Condition

1. Do not open moisture proof bag before the products are ready to use.
2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening.  
Shelf life of non-opened bag is 12 months after the bag sealing date.
3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.





## Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. ( $T_{smin}$ )	150°C
Temperature Max. ( $T_{smax}$ )	200°C
Time ( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )	60-120 seconds
Ramp-up Rate ( $t_L$ to $t_P$ )	3°C/second max.
Liquidous Temperature ( $T_L$ )	217°C
Time ( $t_L$ ) Maintained Above ( $T_L$ )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time ( $t_P$ ) within 5°C of 260°C	30 seconds
Ramp-down Rate ( $T_P$ to $T_L$ )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



## DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

---

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.*
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.*